

X3-Class HiPerFET™ Power MOSFET

IXFN400N15X3

N-Channel Enhancement Mode Avalanche Rated

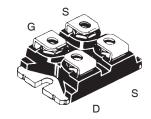


V _{DSS}	=	150V
I _{D25}	=	400A
R _{DS(on)}	≤	$2.5 m\Omega$



Symbol	Test Conditions	Maximum R	Maximum Ratings		
V _{DSS} V _{DGR}	$T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}$ $T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}, R_{GS} = 1\text{M}\Omega$	150 150	V		
V _{GSS} V _{GSM}	Continuous Transient	± 20 ± 30	V V		
I _{D25} I _{L(RMS)}	$T_{\rm C}=25^{\circ}{\rm C}$ (Chip Capability) External Lead Current Limit $T_{\rm C}=25^{\circ}{\rm C}$, Pulse Width Limited by $T_{\rm JM}$	400 200 900	A A A		
I _A E _{AS}	T _c = 25°C T _c = 25°C	200 3.5	A J		
\mathbf{P}_{D}	T _C = 25°C	695	W		
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	50	V/ns		
T _J T _{JM} T _{stg}		-55 +150 150 -55 +150	°C °C °C		
V _{ISOL}	50/60 Hz, RMS $t = 1$ minute $I_{ISOL} \le 1$ mA $t = 1$ second	2500 3000	V~ V~		
M_d	Mounting Torque Terminal Connection Torque	1.5/13 1.3/11.5	Nm/lb.in Nm/lb.in		
Weight		30	g		

SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C \text{ Unless Otherwise Specified})$ Min.		cteristic Values Typ. Max.			
BV _{DSS}	$V_{GS} = 0V, I_D = 3mA$	150			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 8mA$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 200	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ T_{J}	= 125°C		25 1.5	μA mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 200A, Note 1$			2.5	mΩ



G = Gate D = Drain S = Source

Features

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Isolation Voltage 2500V~
- High Current Handling Capability
- Avalanche Rated
- Low R_{DS(on)}

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls



•		Characteristic Values		
		Vin.	Тур.	Max
g _{fs}	$V_{DS} = 10V, I_{D} = 60A, Note 1$ 8	5	145	S
R_{Gi}	Gate Input Resistance		2.15	Ω
C _{iss}			23.7	nF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		3730	pF
C _{rss}			140	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		2200	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		5330	pF
t _{d(on)}	Resistive Switching Times		36	ns
t _r	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 200A$		30	ns
t _{d(off)}	$R_{G} = 10$ (External)		210	ns
t,	Tig = 132 (External)		19	ns
Q _{g(on)}			365	nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 200A$		103	nC
\mathbf{Q}_{gd}			87	nC
R _{thJC}				0.18 °C/W
R _{thCS}			0.05	°C/W

Source-Drain Diode

Symbol (T _J = 25°C, U	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
I _s	$V_{GS} = 0V$			400	Α
SM	Repetitive, Pulse Width Limited by $T_{_{JM}}$			1600	Α
V _{SD}	$I_{\rm F} = 100 {\rm A}, \ V_{\rm GS} = 0 {\rm V}, \ {\rm Note} \ 1$			1.4	V
t _{rr} Q _{RM} }	$I_F = 150A$, -di/dt = 100A/ μ s $V_R = 100V$		132 580 8.8		ns nC A

Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.



400

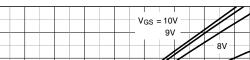


Fig. 1. Output Characteristics @ T_J = 25°C

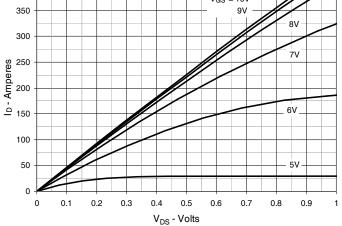


Fig. 2. Extended Output Characteristics @ T_J = 25°C

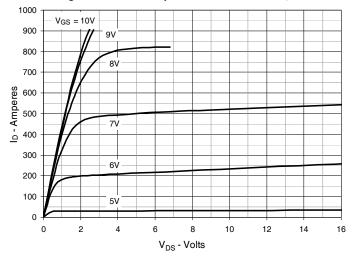


Fig. 3. Output Characteristics @ T_J = 125°C

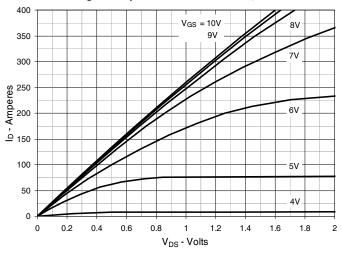


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 200A$ Value vs. **Junction Temperature**

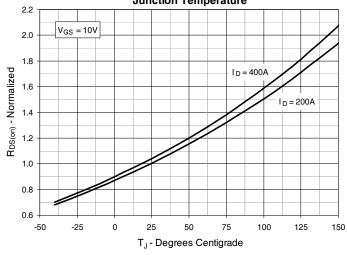


Fig. 5. $R_{DS(on)}$ Normalized to I_D = 200A Value vs.

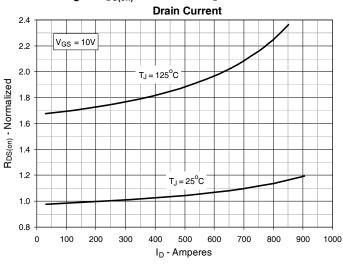
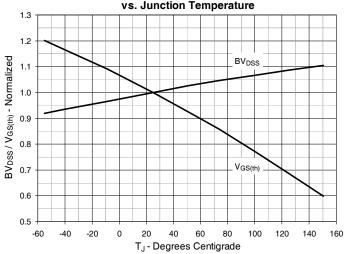
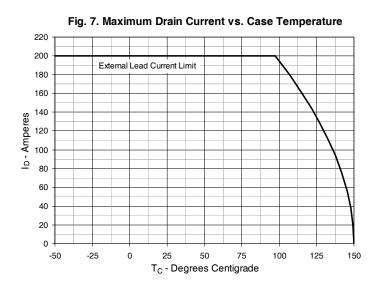
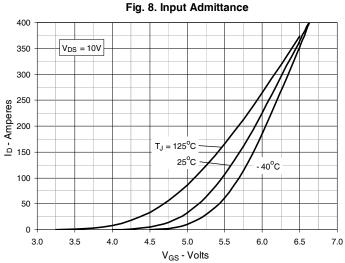


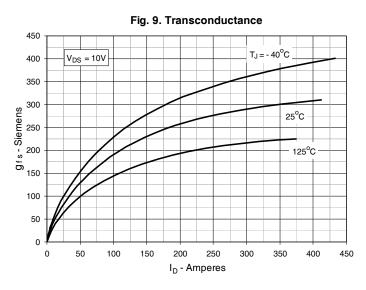
Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature

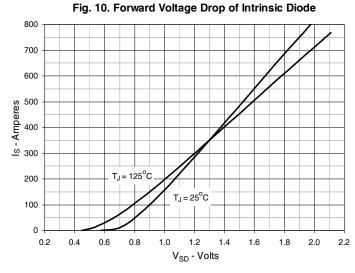


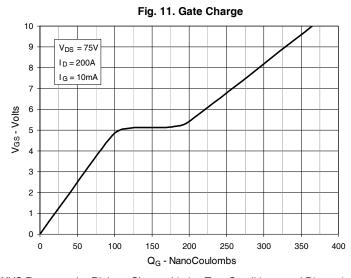
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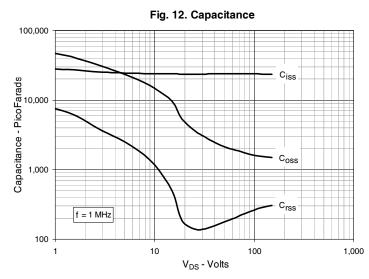






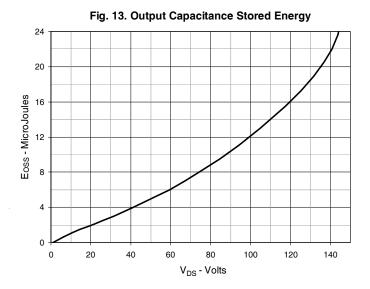






 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.





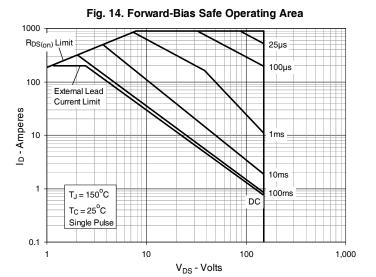
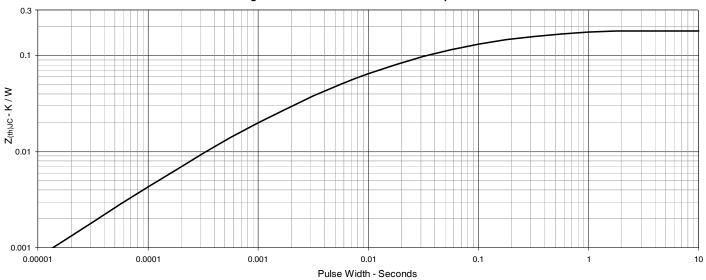
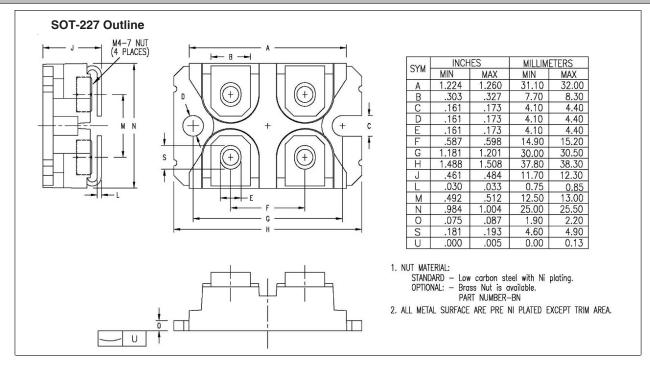


Fig. 15. Maximum Transient Thermal Impedance















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